



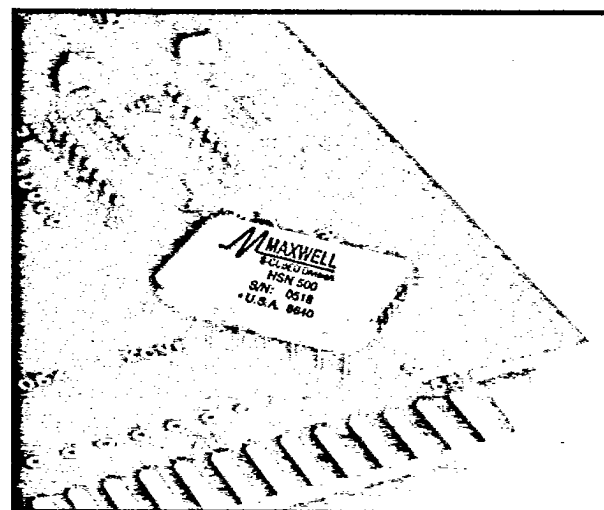
T-65-13

# RADIATION HARDENED HYBRID NUCLEAR EVENT DETECTOR

## Model HSN-500

### FEATURES

- Detects ionizing radiation pulses
- Tested/certified detection threshold level
- Adjustable circumvention period
- 100% testable with built-in test
- Detection threshold adjustability
- Compliant MIL-STD-883 Class B



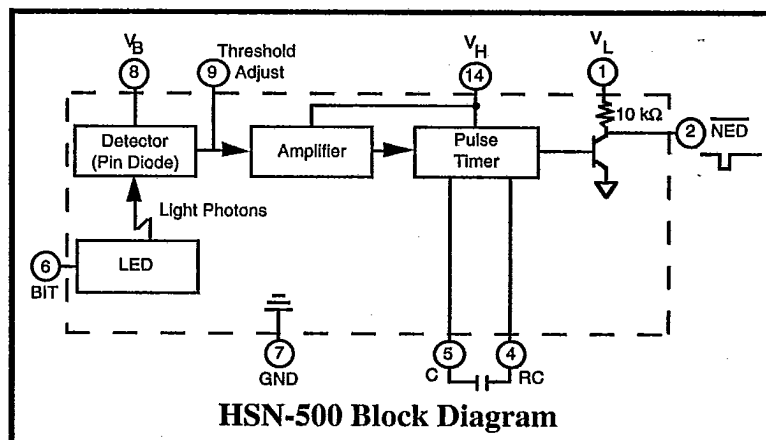
### DESCRIPTION

The S-Cubed Radiation Hardened Hybrid Nuclear Event Detector (NED), Model HSN-500, senses ionizing radiation pulses generated by a nuclear event, such as the detonation of a nuclear weapon, and rapidly switches its outputs from the normal high state to a low state with a propagation delay time of less than 20 ns. The active low Nuclear Event Detection signal ( $\overline{\text{NED}}$ ) is used to initiate a wide variety of circumvention functions, thus preventing upset and burnout of electronic components. The  $\overline{\text{NED}}$  output is also used to initiate both hardware and software recovery. This high-speed, 14-pin hybrid detector is used in electronic systems as a general-purpose circumvention device to protect memory, stop data processing, and drive power supply switches as well as signal clamps.

The HSN-500 is designed to operate through three critical environments: ionizing dose rate [ $10^{12}\text{rad}(\text{Si})/\text{s}$ ], gamma total dose [ $10^6\text{rad}(\text{Si})$ ], and neutron fluence [ $5 \times 10^{13}\text{n}/\text{cm}^2$ ]. In addition, the HSN-500 is designed to function throughout the transient neutron pulse. The hybrid's discrete design ensures a controlled response in these radiation environments as well

as immunity to latchup. The detection level and functionality of a sample of each HSN-500 production lot are tested in an ionizing dose rate environment. A certificate is provided reporting the test results for the production lot.

The detection threshold of the HSN-500 is adjustable within the range of  $2 \times 10^5\text{rad}(\text{Si})/\text{s}$  to  $2 \times 10^7\text{rad}(\text{Si})/\text{s}$ . This detection level can be preset by S-Cubed or adjusted by the user. Less than a 30% variation in detection threshold can be expected over the entire operating temperature range.



## MODEL HSN-500 CHARACTERISTICS

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| ELECTRICAL CHARACTERISTICS | PARAMETER                      | CONDITIONS                                            | MIN  | TYP | MAX   | UNITS         |
|----------------------------|--------------------------------|-------------------------------------------------------|------|-----|-------|---------------|
|                            | Input Power Characteristics:   |                                                       |      |     |       |               |
|                            | $V_H$                          | $V_H = 5.5\text{ V}$<br>STANDBY<br>OPERATIONAL        | 4.5  |     | 5.5   | V             |
|                            | $I_H$                          |                                                       |      |     | 30.0  | mA            |
|                            |                                |                                                       |      |     | 120.0 | mA            |
|                            | $V_L$                          | $V_L = 20.0\text{ V}$<br>STANDBY<br>OPERATIONAL       |      |     | 20.0  | V             |
|                            | $I_L$                          |                                                       |      |     | 100.0 | $\mu\text{A}$ |
|                            |                                |                                                       |      |     | 2.25  | mA            |
|                            | $V_B$                          | STANDBY                                               | 4.5  |     | 20.0  | V             |
|                            | $I_B$                          | STANDBY                                               |      |     | 100.0 | $\mu\text{A}$ |
|                            | BIT <sup>1,2</sup>             |                                                       |      |     |       |               |
|                            | $I_{IH}$                       | $V_{IH} = 4.0\text{ V}$                               |      |     | 25.0  | mA            |
|                            | $t_{PW}$                       | Pin 9 open                                            | 10.0 |     |       | $\mu\text{s}$ |
|                            | Output Signal Characteristics: |                                                       |      |     |       |               |
|                            | NED                            |                                                       |      |     |       |               |
|                            | $V_{OH}$                       | $V_L = 20\text{ V}, I_{OH} = -100\text{ }\mu\text{A}$ | 18.5 |     |       | V             |
|                            | $V_{OL}$                       | $I_{OL} = 10\text{ mA}$                               |      |     | 0.6   | V             |
|                            |                                | $I_{OL} = 100\text{ mA}$                              |      |     | 1.0   | V             |
|                            | Propagation Delay Time $t_D$   |                                                       |      |     | 20    | ns            |

NOTES: 1) BIT Electrical Characteristics are not guaranteed over the radiation range; 2) BIT may not meet specification when only a resistor is used to adjust the detection level. To use BIT in this situation, it is advised that a resistor/capacitor combination is used.

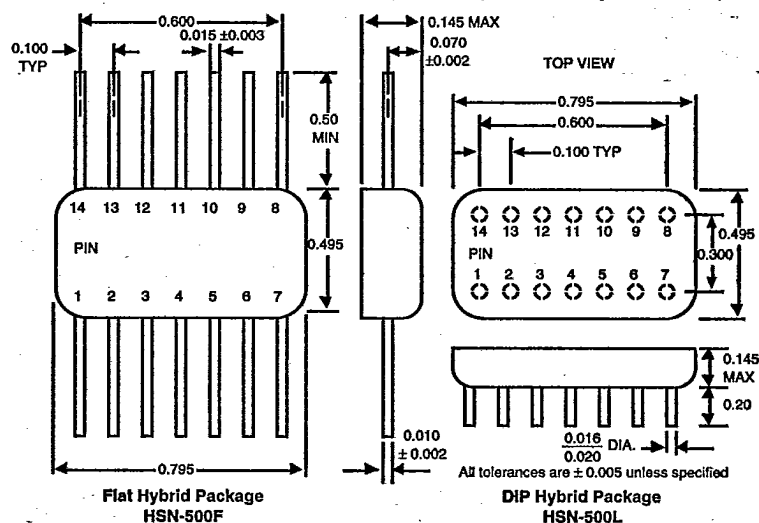
## RADIATION HARDNESS CHARACTERISTICS

|                   |                                 |                   |
|-------------------|---------------------------------|-------------------|
| Dose Rate         |                                 |                   |
| (operate-through) | $1 \times 10^{12}$              | rad(Si)/s         |
| Total Dose        | $1 \times 10^6$                 | rad(Si)           |
| Neutron Fluence   | $5 \times 10^{13}$              | n/cm <sup>2</sup> |
| Approximate       |                                 |                   |
| Detection Range   | $2 \times 10^5 - 2 \times 10^7$ | rad(Si)/s         |

## PIN CONNECTIONS

| Pin# | Function                       |
|------|--------------------------------|
| 1    | Load Voltage, $V_L$            |
| 2    | Nuclear Event Detector, NED    |
| 3    | No Connection                  |
| 4    | External Capacitor             |
| 5    | External Capacitor             |
| 6    | Built In Test, BIT             |
| 7    | Package Ground and Case        |
| 8    | PIN Diode Bias, $V_B$          |
| 9    | Threshold Adjust               |
| 10   | No Connection                  |
| 11   | No Connection                  |
| 12   | No Connection                  |
| 13   | No Connection                  |
| 14   | Hardened Supply Voltage, $V_H$ |

## MECHANICAL DIMENSIONS



Specifications subject to change without notice.

Information Contact:  
Joan McCrosson  
Products Manager  
TEL: (619) 450-2537  
FAX: (619) 450-1029

S-Cubed  
3020 Callan Road  
San Diego, CA 92121-1109

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**MAXWELL**  
S-CUBED Division